

Synchronous Rectification Driver IC

General Description

AT6901Z is a secondary side Synchronous Rectification driver IC to drive SR MOS replaces Schottky rectification diode for higher efficiency. With adaptive dead time control method, AT6901Z could operates in DCM and CCM safely without cross conduction issue. In system light load condition, AT6901Z enter light load mode and stop Gate switching result to less standby power loss.

The devices is available in SOT23_5L package and require few external devices for operation.

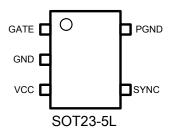
Features

- □ Support Flyback , Forward Freewheeling Rectification operate in Multi-Mode DCM/CCM
- Quick Transient Response
- ☐ Intelligent Dead Time control
- □ VCC range from 4.7V~36V
- 350uA Low light Load Operation Current
- □ Sourcing 1A/Sinking 1.5A High Drive Capability Driver
- ☐ SOT23-5L Package

Applications

- □ Server and Desktop Power Supplies
- □ Telecom Power Supplies
- Adaptor and Battery Charger
- □ Open Frame Switching Power Supplies

Pin Configuration



Ordering and Marking Information

Order Number	Package	Top Marking		
AT6901ZST5	SOT23-5L	ZD		

Note: Aplustek products are compatible with the current IPC/JEDEC

J-STD-020 requirement. They are halogen-free, RoHS compliant
and 100% matte tin (Sn) plating that are suitable for use in SnPb or
Pb-free soldering processes.



Typical Application Circuit

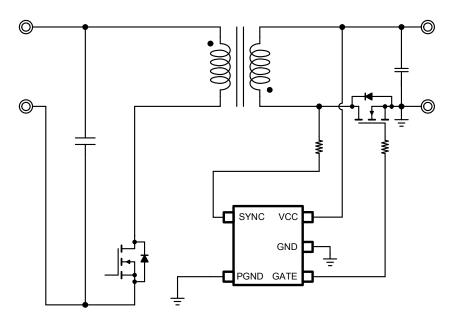


Fig1.Flyback Low Side Synchronous Rectification

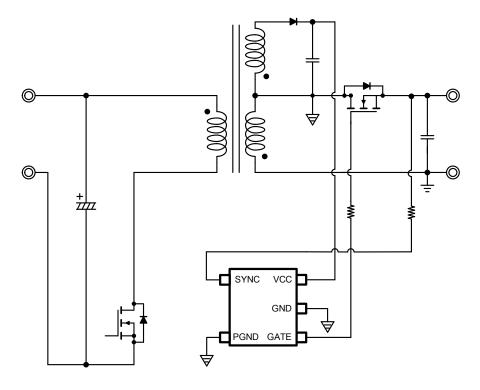


Fig2.Flyback High Side Synchronous Rectifier



Typical Application Circuit

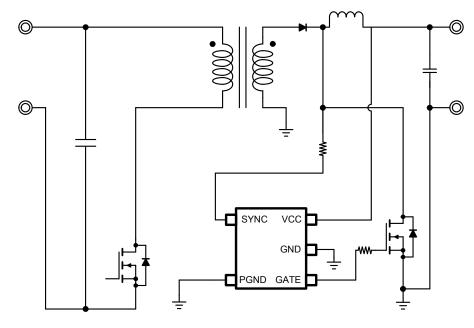
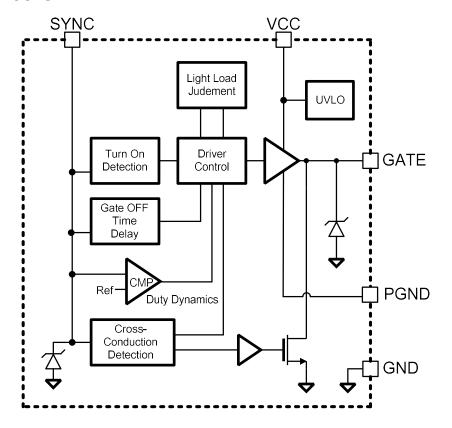


Fig3.Foward Freewheeling Rectification

Function Blocks







Function Pin Description

No.	Pin Name	Pin Function
1	GATE	Gate Driving pin. Connect to MOSFET gate pin directly or through a
		resistor.
2	GND	Ground.
3	VCC	Supply Voltage pin.
4	SYNC	The SYNC pin is used to detect VDS of SR MOSFET
5	PGND	Gate Driver Power Ground.

Absolute Maximum Ratings

(Note1)

(1.010.1)	
Supply Input Voltage, V_{cc}	
SYNC to GND DC	
Gate to GND DC	
Storage Temperature Range	
Junction Temperature	
Lead Temperature Range(Soldering 10sec)	260°C
ESD Rating (Note2)	
HBM(Human Body Mode)	2KV
MM(Machine Mode)	200V
Thermal Characteristics	

Thermal Characteristics

Package Thermal Resistance (Note3)

Power Dissipation, F	² D @ TA = 25°C	
SOP23-6I		W

SOT23-5L θ_{JA} ------200°C/W





Electrical Characteristics

($V_{\rm CC}$ = 12V, $T_{\rm A}$ = +25°C unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
VCC Supply Input Section			•	'	'	-
VCC operation range			4.7		36	V
VCC UVLO threshold	VCC,on	VCC Rising		4.4		V
	VCC,off	VCC Falling		4.2		V
Over Voltage Protection Voltage	VCC,ovp		36	38	40	V
Normal Operation Current	lop	CL=5nF, 50kHz Switching		3.8		mA
		Frequency				
Light Load current	ICC_LL	SYNC=0V,VCC=0V		350		uA
SYNC Section			•		•	
Positive Clamp Voltage		Isouce=1mA		4.1		V
Negative Clamp Voltage		Isink=1mA		-0.6		V
Arming Threshold for Next Gate	Vsync_arm			2.5		V
On						
Threshold for On Detection	Vsync_det			1		V
Threshold for Diode Detection				-8		mV
Input Impedance to GND	Rsync			10		kohm
Recommend SYNC Voltage as	Vsync_recom	for MOS Drain to SYNC	1.6		2.1	V
MOS Drain Voltage = Output		Resistor Setting				
Voltage						
Recommend SYNC Resistor to	Rsync_ext	Output Voltage=5V		18		kohm
MOS Drain		Output Voltage=12V		56		kohm
Blanking Time of SYNC Sense				1		uS
after SYNC arming						
TSD Section						
Internal Thermal Protection	TSD_int			150		Degre
						e
Hysteresis of Thermal	TSD_int_hys			20		Degre
Protection						e





Electrical Characteristics

($V_{\rm CC}$ = 12V, $T_{\rm A}$ = +25°C unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Gate Section			'	•	1	•
Time period between Gate turn off	Tgd			640		nS
to SYNC high						
Off time to enter sleep mode	Tslp_entry	for burst mode operation		100		uS
Number of Cycle to Exit sleep				28		Cycle
mode						
Maximum On Time	Ton_max			25		uS
Minimum On Time	Ton_min			410		nS
Output Voltage Low	Vol	VCC=12V, Io=20mA			0.05	٧
		Sinking				
Output Voltage High	Voh	VCC=12V, Io=20mA	8			V
		Sourcing				
Rising Time	tr	CL=5nF		30		nS
Falling Time	tf	CL=5nF		12		nS
Gate Voltage Clamping	Vgate(clamp)	VCC=36V	9.5	11.5	13.5	V
Disable Pull High PMOS	Vpmos_on			10.5		V
Pull Low Impedance				10		kohm
Maximum Switching	fsw_max		400			kHz
Frequency						